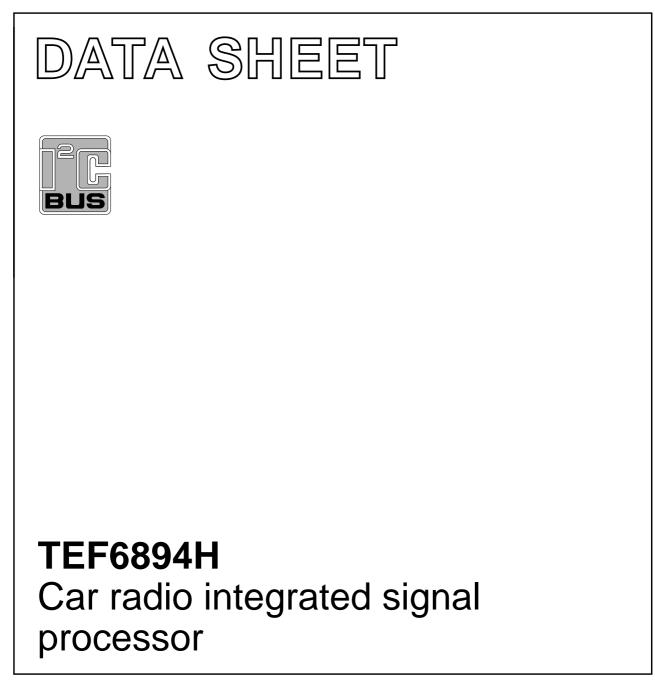
INTEGRATED CIRCUITS



Product specification

2003 Oct 21



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Product specification

Car radio integrated signal processor

TEF6894H

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Data byte 3; USN and WAM

Data byte 2; LEVEL

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FEATURES

1.1 General

1

- High integration
- No external components except coupling capacitors for signal inputs and outputs

Car radio integrated signal processor

• QFP44 package with small Printed-Circuit Board (PCB) footprint.

1.2 I²C-bus

- Fast mode 400 kHz l²C-bus, interfaces to logic levels ranging from 2.5 to 5 V
- Gated I²C-bus loop through to tuner IC
 - Eases PCB layout (crosstalk)
 - Allows mix of 400 kHz and 100 kHz busses
 - Low bus load reduces crosstalk
 - Buffered I/O circuit
 - Supply voltage shift between both buses allowed.
- Shortgate function offers easy control with automatic gating of a single transmission; suited for TEA684x
- Autogate function offers transparent microcontroller control with automatic on/off gating (programmable address).

1.3 Stereo decoder

- FM stereo decoder with high immunity to birdy noise and excellent pilot cancellation
- Integrated IF roll-off correction controlled via I²C-bus
- De-emphasis selectable between 75 and 50 μs via $I^2C\text{-bus}.$

1.4 Noise blanking

- New fully integrated AM noise blanker with excellent performance
- Fully integrated FM noise blanker with superior performance.

1.5 Weak signal processing

- FM weak signal processing with detectors for RF level, Ultrasonic Noise (USN) and Wideband AM (WAM) information
- AM weak signal processing with detectors for level information
- AM processing with soft mute and High Cut Control (HCC)
- FM processing with soft mute, stereo blend and HCC
- Setting of the sensitivity of the detectors and start and slope of the control functions via I²C-bus
- Weather band de-emphasis
- Level, USN and WAM read-out via l²C-bus (signal quality detectors)
- Full support of tuner AF update functions with TEA684x tuner ICs, FM audio processing holds the detectors for the FM weak signal processing in their present state during RDS updating.



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1.6 Tone/volume part

- Input selector for four inputs:
 - Two external stereo inputs (CD and TAPE)
 - One mono input (PHONE)
 - One internal stereo input (AM or FM).
- Integrated tone control and audio filters without external components
- Volume control from +20 to -79 dB in 1 dB steps; programmable 20 dB loudness control included
- Programmable loudness control with bass boost or as bass and treble boost
- Treble control from -14 to +14 dB in 2 dB steps
- Bass control from –14 to +14 dB in 2 dB steps with selectable characteristics
- Good undistorted performance for any step size, including mute
- Audio Step Interpolation (ASI) available for the following audio controls:
 - Mute
 - Loudness
 - Volume/balance
 - Bass
 - Fader.
- ASI also realizes Alternative Frequency (AF) mute for inaudible RDS update
- Integrated beep generator
- Navigation (NAV) input
- Output mixer circuit for beep or NAV signal at output stages.

3 ORDERING INFORMATION

TYPE		PACKAGE				
NUMBER	NAME	DESCRIPTION	VERSION			
TEF6894H	QFP44	plastic quad flat package; 44 leads (lead length 1.3 mm); body $10 \times 10 \times 1.75$ mm	SOT307-2			

2 GENERAL DESCRIPTION

The TEF6894H is a monolithic BiMOS integrated circuit comprising the stereo decoder function, weak signal processing and ignition noise blanking facility for AM and FM combined with input selector and tone/volume control for AM and FM car radio applications. The device operates with a supply voltage of 8 to 9 V.

TEF6894H

4 QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{CC}	supply voltage		8.0	8.5	9.0	V
I _{CC}	supply current	normal mode	-	24	_	mA
		standby	-	15	-	mA
Stereo decode	r path					
α_{cs}	channel separation	f _{FMMPX} = 1 kHz	40	-	_	dB
S/N	signal-to-noise ratio	f _{FMMPX} = 20 Hz to 15 kHz	75	-	_	dB
THD	total harmonic distortion	FM mode; f _{FMMPX} = 1 kHz	-	-	0.3	%
Tone/volume o	control					
V _{i(max)} (rms)	maximum input voltage level at pins TAPEL, TAPER, CDL, CDR, CDCM, PHONE and PHCM (RMS value)	THD = 0.1%; $G_{vol} = -6 \text{ dB}$	2	_	_	V
V _{i(NAV)(max)(rms)}	maximum input voltage level at pin NAV (RMS value)	THD = 1%; f _{NAV} = 1 kHz	0.3	-	-	V
THD	total harmonic distortion	TAPE and CD inputs; $f_{audio} = 20$ Hz to 20 kHz; $V_i = 1 V$ (RMS)	-	0.01	0.1	%
G _{vol}	volume/balance gain control	maximum setting	-	20	-	dB
		minimum setting	-	-59	-	dB
G _{step(vol)}	step resolution gain (volume)		-	1	-	dB
G _{loudness}	loudness gain control	f _{loudness(low)} = 50 Hz; high boost on maximum setting; 1 kHz tone minimum setting; 1 kHz tone	_	0	_	dB dB
G _{treble}	treble gain control	maximum setting	_	14	_	dB
Otreble		minimum setting	_	-14	_	dB
G _{step(treble)}	step resolution gain (treble)		_	2	_	dB
G _{bass}	bass gain control	maximum setting; symmetrical boost	_	14	_	dB
- 5000		minimum setting; asymmetrical cut	_	-14	_	dB
G _{step(bass)}	step resolution gain (bass)		_	2	_	dB

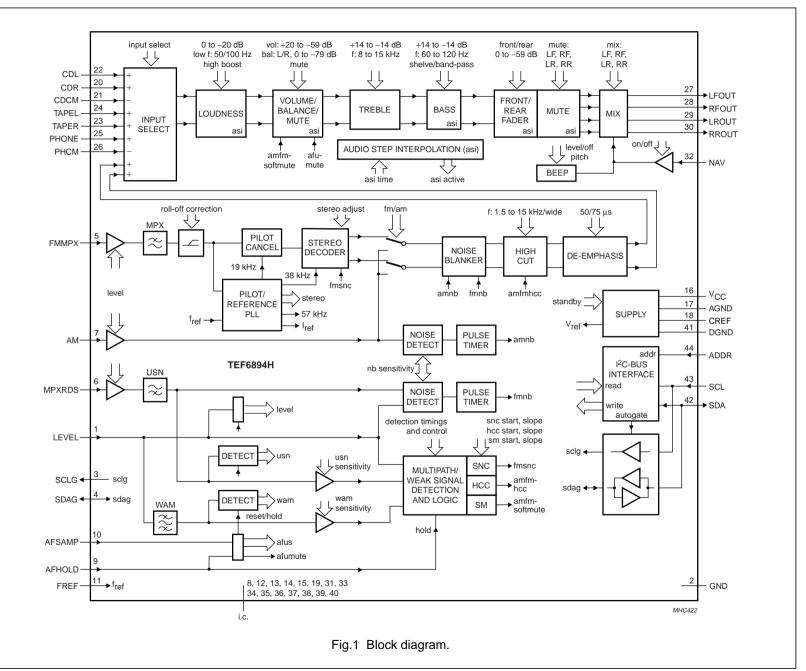
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Product specification

Car radio integrated signal processor

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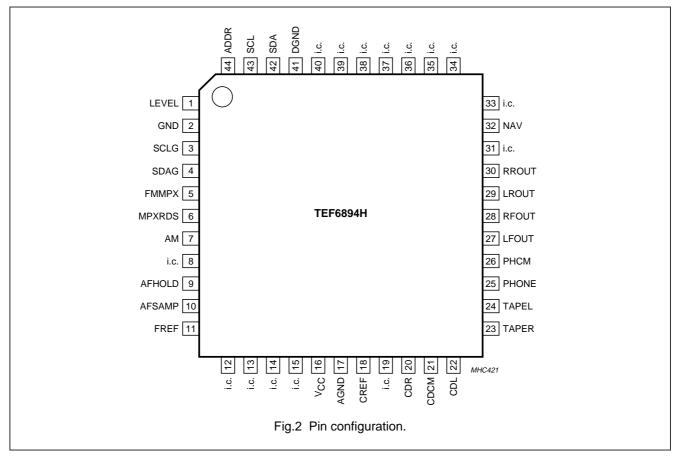
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6 PINNING

SYMBOL	PIN	DESCRIPTION
LEVEL	1	level detector input
GND	2	ground
SCLG	3	gated I ² C-bus clock port
SDAG	4	gated I ² C-bus data port
FMMPX	5	FM-MPX input for audio processing
MPXRDS	6	FM-MPX input for weak signal processing and noise blanker
AM	7	AM audio input
i.c.	8	internally connected
AFHOLD	9	FM weak signal processing hold input
AFSAMP	10	trigger signal input for quality measurement
FREF	11	reference frequency input 75.4 kHz
i.c.	12	internally connected
i.c.	13	internally connected
i.c.	14	internally connected
i.c.	15	internally connected
V _{CC}	16	supply voltage
AGND	17	analog ground
CREF	18	reference voltage capacitor
i.c.	19	internally connected
CDR	20	CD right input
CDCM	21	CD common input
CDL	22	CD left input
TAPER	23	tape right input
TAPEL	24	tape left input
PHONE	25	phone input
PHCM	26	phone common input
LFOUT	27	left front output
RFOUT	28	right front output
LROUT	29	left rear output
RROUT	30	right rear output
i.c.	31	internally connected
NAV	32	audio input for navigation voice signal
i.c.	33	internally connected
i.c.	34	internally connected
i.c.	35	internally connected
i.c.	36	internally connected
i.c.	37	internally connected
i.c.	38	internally connected
i.c.	39	internally connected
i.c.	40	internally connected

SYMBOL	PIN	DESCRIPTION
DGND	41	digital ground
SDA	42	I ² C-bus data input or output
SCL	43	I ² C-bus clock input
ADDR	44	address select input



7 FUNCTIONAL DESCRIPTION

7.1 Stereo decoder

The FMMPX input is the input for the MPX signal from the tuner. The input gain can be selected in three settings to match the input to the RF front-end circuit. A fourth setting is used for weather band mode, which may require a gain of 23.5 dB.

A low-pass filter provides the necessary signal delay for FM noise blanking and suppression of high frequency interferences into the stereo decoder input. The output signal of this filter is fed to the roll-off correction circuit. This circuit compensates the frequency response caused by the low-pass characteristic of the tuner circuit with its IF filters. The roll-off correction circuit is adjustable in four settings to compensate different frequency responses of the tuner part.

The MPX signal is decoded in the stereo decoder part. A PLL is used for the regeneration of the 38 kHz subcarrier. The fully integrated oscillator is adjusted by a digital auxiliary PLL into the capture range of the main PLL. The auxiliary PLL needs an external reference frequency (75.4 kHz) which is provided by the tuner ICs of the NICE family (TEA684x). The required 19 and 38 kHz signals are generated by division of the oscillator output signal in a logic circuit. The 19 kHz quadrature phase signal is fed to the 19 kHz phase detector, where it is compared with the incoming pilot tone. The DC output signal of the phase detector controls the oscillator (PLL).

The pilot detector is driven by an internally generated in-phase 19 kHz signal. Its pilot dependent voltage activates the stereo indicator bit and sets the stereo decoder to stereo mode. The same voltage is used to control the amplitude of an anti-phase internally generated 19 kHz signal. In the pilot canceller, the pilot tone is compensated by this anti-phase 19 kHz signal.

The signal is then decoded in the decoder part. The side signal is demodulated and combined with the main signal to the left and right audio channels. A fine adjustment of the roll-off compensation is done by adjusting the gain of the L-R signal in 16 steps. A smooth mono to stereo takeover is achieved by controlling the efficiency of the matrix by the FMSNC signal from the weak signal processing block.

7.2 FM and AM noise blanker

The FM/AM switch selects the output signal of the stereo decoder (FM mode) or the signal from the AM input for the noise blanker block. In FM mode the noise blanker operates as a sample and hold circuit, while in AM mode it mutes the audio signal during the interference pulse. The blanking pulse which triggers the noise blanker is generated in the noise detector block.

7.3 High cut control and de-emphasis

The High Cut Control (HCC) part is a low-pass filter circuit with eight different static roll-off response curves. The cut-off frequencies of these filter curves can be selected by I²C-bus to match different application requirements. The HCC circuit also provides a dynamic control of the filter response. This function is controlled by the AMFMHCC signal from the weak signal processing.

The signal passes the de-emphasis block with two de-emphasis values (50 and 75 μ s), which can be selected via I²C-bus, and is fed to the input selector.

7.4 Noise detector

7.4.1 FM NOISE DETECTOR

The trigger signal for the FM noise detector is derived from the MPXRDS input signal and the LEVEL signal. In the MPXRDS path a four pole high-pass filter (100 kHz) separates the noise spikes from the wanted MPX signal. Another detector circuit triggers on noise spikes on the level voltage. The signals of both detectors are combined to achieve a reliable trigger signal for the noise blanker. AGC circuits in the detector part control the gain depending on the average noise in the signals to prevent false triggering. The sensitivity of the triggering from the MPXRDS signal can be adjusted in four steps, the triggering from the LEVEL signal in three steps.

7.4.2 AM NOISE DETECTOR

The trigger pulse for the AM noise blanker is derived from the AM audio signal. The noise spikes are detected by a slew rate detector, which detects excessive slew rates which do not occur in normal audio signals. The sensitivity of the AM noise blanker can be adjusted in four steps.

7.5 Multipath/weak signal processing

The multipath (MPH)/weak signal processing block detects quality degradations in the incoming FM signal and controls the processing of the audio signal accordingly. There are three different quality criteria:

- The average value of the level voltage
- The AM components on the level voltage [Wideband AM (WAM)]
- The high frequency components in the MPX signal [Ultrasonic Noise (USN)].

The level voltage is converted to a digital value by an 8-bit analog-to-digital converter. A digital filter circuit (WAM filter) derives the wideband AM components from the level signal. The high frequency components in the MPX signals are measured with an analog-to-digital converter (USN ADC) at the output of the 100 kHz high-pass filter in the MPXRDS path.

The values of these three signals are externally available via the $\ensuremath{\mathsf{l}}^2\ensuremath{\mathsf{C}}\xspace$ bus.

In the weak signal processing block the three digital signals are combined in a specific way and used for the generation of control signals for soft mute, stereo blend (stereo noise control, FMSNC) and high cut control (AMFMHCC).

The sensitivities of the detector circuits (WAM and USN) are adjustable via the l^2 C-bus.

Also the start values and the slopes of the control functions soft mute, stereo blend and high cut control can be set via the I^2C -bus.

Soft mute, stereo blend and HCC are set on hold during the AF updating (quality check of alternative frequency) to avoid an influence of the tuning procedure on the weak signal processing conditions.

In AM mode the soft mute and high cut control are available too, the weak signal block is controlled by the average value of the level voltage.

7.6 Tone/volume control

The tone/volume control part consists of the following stages:

- Input selector
- Loudness control
- Volume/balance control with muting
- Treble control
- Bass control
- Fader and output mute
- Beep generator
- NAV input
- Output mixer.

The settings of all stages are controlled via the I²C-bus.

The stages input selector, loudness, volume/balance, bass, and fader/output mute include the Audio Step Interpolation (ASI) function. This minimizes pops by smoothing the transitions in the audio signal during the switching of the controls. The transition time of the ASI function is programmable by I²C-bus in four steps.

7.6.1 INPUT SELECTOR

The input selector selects one of four input sources:

- Two external stereo inputs (CD and TAPE)
- One external mono input (PHONE)
- One internal stereo input (AM/FM).

7.6.2 LOUDNESS

The output of the input selector is fed into the loudness circuit. Four different loudness curves can be selected via the l^2 C-bus. The control range is between 0 and -20 dB with a step size of 1 dB; see Figs 16 to 19.

7.6.3 VOLUME/BALANCE

The volume/balance control is used for volume setting and also for balance adjustment. The control range of the volume/balance control is between +20 and -59 dB in steps of 1 dB.

The combination of loudness and volume/balance realizes an overall control range of +20 to -79 dB.

7.6.4 TREBLE

The signal is then fed to the treble control stage. The control range is between +14 and -14 dB in steps of 2 dB. Figure 20 shows the control characteristic. Four different filter frequencies can be selected.

7.6.5 BASS

The characteristic of the bass attenuation curves can be set to shelve or band-pass. Four different frequencies can be selected as centre frequency of the band-pass curve. Figures 21 and 22 show the bass curves with a band-pass filter frequency of 60 Hz. The control range is between +14 and -14 dB in steps of 2 dB.

7.6.6 FADER/MUTE

The four fader/mute blocks are located at the end of the tone/volume chain. The control range of these attenuators is 0 to -59 dB. The step size is:

- 1 dB between 0 and -15 dB
- 2.5 dB between -15 and -45 dB
- 3 dB between -45 and -51 dB
- 4 dB between -51 and -59 dB.
- 7.6.7 BEEP GENERATOR AND NAV INPUT WITH OUTPUT MIXER

The output mixer circuit can add an additional audio signal to any of the four outputs together with the main signal or instead of the main signal.

The additional signal can be generated internally by the beep generator with four different audio frequencies or applied to the NAV input, for instance a navigation voice signal.

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8 LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CC}	supply voltage		-0.3	+10	V
Vi	input voltage for any pin		-0.3	V _{CC} + 0.3	V
T _{stg}	storage temperature		-65	+150	°C
T _{amb}	ambient temperature		-40	+85	°C
V _{esd}	electrostatic discharge voltage	note 1	-200	+200	V
		note 2	-2000	+2000	V

Notes

- 1. Machine model (R = 0 Ω , C = 200 pF).
- 2. Human body model (R = $1.5 \text{ k}\Omega$, C = 100 pF).

9 THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	61	K/W

10 CHARACTERISTICS

FM part: $f_{FMMPX} = 1 \text{ kHz}$ at $V_{FMMPX} = 767 \text{ mV}$ (RMS); pilot off (100% FM). AM part: $f_{AM} = 1 \text{ kHz}$ at $V_{AM} = 967 \text{ mV}$ (RMS) (100% AM). Treble: 10 kHz filter frequency. Bass: 60 Hz filter frequency. Loudness: 50 Hz filter frequency; treble loudness on. $V_{CC} = 8.5 \text{ V}$; $T_{amb} = 25 \text{ °C}$; see Fig.23; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{CC}	supply voltage		8.0	8.5	9.0	V
I _{CC}	supply current	normal mode	-	24	-	mA
		standby	-	15	-	mA
Logic pins			•			
V _{IH}	HIGH-level input voltage	pins SDA, SCL, ADDR and SDAG	1.75	-	5.5	V
		pins AFHOLD and AFSAMP	1.75	-	5.5	V
V _{IL}	LOW-level input voltage	pins SDA, SCL, ADDR and SDAG	-0.2	-	+1.0	V
		pins AFHOLD and AFSAMP	-0.2	_	+1.0	V
V _{OL}	LOW-level output voltage	pin SCLG; I _{OL} = 3 mA; note 1	-	-	0.4	V
		pin SDA; I _{OL} = 3 mA	-	-	0.4	V
Stereo decod	er and AM path		•			
V _{o(FM)(rms)}	FM mono output voltage (RMS value) on pins LFOUT and RFOUT	f_{FMMPX} = 1 kHz; 91% FM modulation without pilot (V _{FMMPX} = 698 mV)	750	950	1200	mV
V _{o(AM)(rms)}	AM output voltage (RMS value) on pins LFOUT and RFOUT	$f_{AM} = 1 \text{ kHz}; V_{AM} = 870 \text{ mV};$ 90% AM modulation	800	1080	1360	mV

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G _i	input gain on	see Table 36				
	pins FMMPX, MPXRDS	ING[1:0] = 00; all inputs	_	0	_	dB
	and AM	ING[1:0] = 01; all inputs	_	3	_	dB
		ING[1:0] = 10; all inputs	_	6	_	dB
		ING[1:0] = 11; FMMPX	_	23.5	_	dB
		ING[1:0] = 11; MPXRDS and AM	_	0	_	dB
α _{cs}	channel separation	f _{FMMPX} = 1 kHz	40	_	_	dB
gc(L-R)	roll-off correction for coarse adjustment of separation	see Table 20; measure 1 kHz level for L – R modulation; compare to 1 kHz level for L + R modulation				
		CSR[1:0] = 00	-	0	-	dB
		CSR[1:0] = 01	-	0.4	-	dB
		CSR[1:0] = 10	-	0.8	-	dB
		CSR[1:0] = 11	_	1.2	-	dB
g _{f(L-R)}	stereo adjust for fine adjustment of separation	see Table 21; measure 1 kHz level for L – R modulation; compare to 1 kHz level for L + R modulation				
		CSA[3:0] = 0000	-	0	-	dB
		CSA[3:0] = 0001	-	0.2	-	dB
		:	_	:	-	dB
		CSA[3:0] = 1110	_	2.8	-	dB
		CSA[3:0] = 1111	_	3.0	-	dB
S/N	signal-to-noise ratio	$ f_{FMMPX} = 20 \text{ Hz to } 15 \text{ kHz}; \\ referenced to 1 \text{ kHz at } 91\% \text{ FM} \\ modulation; DEMP = 1 \\ (\tau_{de-em} = 50 \ \mu s) $	75	-	-	dB
THD	total harmonic distortion	FM mode				
		f _{FMMPX} = 1 kHz	_	_	0.3	%
		V _{FMMPX} = 50%; L; pilot on	_	_	0.3	%
		V _{FMMPX} = 50%; R; pilot on	_	_	0.3	%
V _{o(bal)}	mono channel balance $\frac{V_{oL}}{V_{oR}}$	FM mode	-1	-	+1	dB
α ₁₉	pilot signal suppression	9% pilot; $f_{pilot} = 19$ kHz; referenced to 1 kHz at 91% FM modulation; DEMP = 1 ($\tau_{de-em} = 50 \ \mu s$)	40	50	-	dB
α	subcarrier suppression	modulation off; referenced to 1 kHz at 91% FM modulation				
		f _{sc} = 38 kHz	35	50	-	dB
		f _{sc} = 57 kHz	40	_	-	dB
		f _{sc} = 76 kHz	50	60	_	dB
PSRR	power supply ripple rejection	$\label{eq:FM} \begin{array}{l} \mbox{FM mode; } f_{ripple} = 100 \mbox{ Hz;} \\ \mbox{V}_{CC(AC)} = \mbox{V}_{ripple} = 100 \mbox{ mV} \mbox{ (RMS)} \end{array}$	24	-	-	dB

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
ΔV_{out}	frequency response	FM mode				
		f _{FMMPX} = 20 Hz	-0.5	-	+0.5	dB
		f _{FMMPX} = 15 kHz	-0.5	-	+0.5	dB
f _{cut-off(de-em)}	cut-off frequency of	-3 dB point; see Fig.15				
	de-emphasis filter	$DEMP = 1 \ (\tau_{de-em} = 50 \ \mu s)$	_	3.18	-	kHz
		$DEMP = 0 \; (\tau_{de-em} = 75 \; \mu s)$	-	2.12	-	kHz
m _{i(pilot)(rms)}	pilot threshold modulation	stereo				
	for automatic switching by	on	-	4.0	5.5	%
	pilot input voltage (RMS value)	off	1.3	2.7	-	%
hys _{pilot}	hysteresis of pilot threshold voltage		-	2	-	dB
V _{ref(min)}	minimum reference input voltage		-	-	30	mV
f _{ref}	reference frequency for stereo PLL		75361	75368	75375	Hz
Noise blanke	r		•			
FM PART						
t _{sup(min)}	minimum suppression time		-	15	-	μs
V _{MPXRDS(M)}	noise blanker sensitivity at MPXRDS input	see Table 37; $t_{pulse} = 10 \ \mu s$; repetition frequency f = 300 Hz				
	(peak value of noise	NBS[1:0] = 00	-	90	-	mV
	pulses)	NBS[1:0] = 01	-	150	-	mV
		NBS[1:0] = 10	-	210	-	mV
		NBS[1:0] = 11	-	270	-	mV
V _{LEVEL(M)}	noise blanker sensitivity at LEVEL input	see Table 40; $t_{pulse} = 10 \ \mu s$; repetition frequency f = 300 Hz				
	(peak value of noise	NBL[1:0] = 00	-	9	-	mV
	pulses)	NBL[1:0] = 01	-	18	-	mV
		NBL[1:0] = 10	_	28	-	mV
AM PART				1		
t _{sup(min)}	minimum suppression time		-	200	-	μs
M _{AM}	noise blanker sensitivity	see Table 37; f _{audio} = 2 kHz				
		NBS[1:0] = 00	-	110	-	%
		NBS[1:0] = 01	-	140	-	%
		NBS[1:0] = 10	-	175	-	%
		NBS[1:0] = 11	-	220	-	%

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Weak signal p	processing		1	1		1
DETECTORS						
V _{eq(USN)}	USN sensitivity equivalent level voltage	see Fig.5; $f_{MPXRDS} = 150 \text{ kHz}$; $V_{MPXRDS} = 250 \text{ mV} (RMS)$; HCMP = 1; note 2				
		USS[1:0] = 00	_	2.5	_	V
		USS[1:0] = 01	_	2	_	V
		USS[1:0] = 10	_	1.5	_	V
		USS[1:0] = 11	_	0.5	_	V
V _{eq(WAM)}	WAM sensitivity equivalent level voltage	see Fig.6; $V_{LEVEL} = 200 \text{ mV}$ (p-p) at f = 21 kHz on the level voltage; HCMP = 1; note 2				
		WAS[1:0] = 00	-	2.5	_	V
		WAS[1:0] = 01	-	2	_	V
		WAS[1:0] = 10	-	1.5	_	V
		WAS[1:0] = 11	-	0.5	_	V
t _{LEVEL(attack)}	level detector attack time	see Table 24; LETF = 0; SEAR = 0				
	(soft mute and HCC)	LET[1:0] = 00	-	3	_	s
		LET[1:0] = 01	-	3	_	s
		LET[1:0] = 10	-	1.5	_	s
		LET[1:0] = 11	-	0.5	_	s
		see Table 24; LETF = 1; SEAR = 0				
		LET[1:0] = 00	-	0.5	_	s
		LET[1:0] = 01	-	0.17	_	s
		LET[1:0] = 10	-	0.06	_	s
		LET[1:0] = 11	-	0.06	_	s
		search mode; SEAR = 1	-	60	-	ms
t _{LEVEL(decay)}	level detector decay time	see Table 24; LETF = 0; SEAR = 0				
	(soft mute and HCC)	LET[1:0] = 00	-	3	_	s
		LET[1:0] = 01	-	6	_	s
		LET[1:0] = 10	-	1.5	_	s
		LET[1:0] = 11	_	1.5	_	s
		see Table 24; LETF = 1; SEAR = 0				
		LET[1:0] = 00	-	0.5	-	s
		LET[1:0] = 01	-	0.5	-	s
		LET[1:0] = 10	-	0.17	-	s
		LET[1:0] = 11	-	0.06	-	s
		search mode; SEAR = 1	_	60	_	ms

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
t _{MPH(attack)}	multipath detector attack	see Table 25; SEAR = 0				
(time (SNC)	MPT[1:0] = 00	_	0.5	_	s
		MPT[1:0] = 01	_	0.5	_	s
		MPT[1:0] = 10	_	0.5	_	s
		MPT[1:0] = 11	_	0.25	_	s
		search mode; SEAR = 1	-	60	-	ms
t _{MPH(decay)}	multipath detector decay	see Table 25; SEAR = 0				
	time (SNC)	MPT[1:0] = 00	-	12	_	s
		MPT[1:0] = 01	_	24	-	s
		MPT[1:0] = 10	-	6	-	s
		MPT[1:0] = 11	_	6	-	s
		search mode; SEAR = 1	-	60	-	ms
t _{USN(attack)}	USN detector attack time (soft mute and SNC)		-	1	-	ms
t _{USN(decay)}	USN detector decay time (soft mute and SNC)		-	1	-	ms
ΔUSS	USN detector desensitization	USN sensitivity setting (USS) versus level voltage (USN sensitivity setting is automatically reduced as level voltage decreases)				
		V _{LEVEL} > 1.25 V	-	-	3	-
		1.25 V > V _{LEVEL} > 1.125 V	-	-	2	-
		1.125 V > V _{LEVEL} > 1.0 V	-	-	1	-
		$1.0 \text{ V} > \text{V}_{\text{LEVEL}}$	-	-	0	-
t _{WAM(attack)}	WAM detector attack time (SNC)		-	1	-	ms
t _{WAM(decay)}	WAM detector decay time (SNC)		-	1	_	ms
t _{peak(USN)(attack)}	peak detector for USN attack time for read-out via I ² C-bus		-	1	-	ms
t _{peak(USN)(decay)}	peak detector for USN decay time for read-out via I ² C-bus		-	10	-	ms
t _{peak(WAM)(attack)}	peak detector for WAM attack time for read-out via I ² C-bus		-	1	-	ms
t _{peak(WAM)(decay)}	peak detector for WAM decay time for read-out via I ² C-bus		-	10	-	ms

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
CONTROL FUNC	TIONS		ļ	1		4
V _{start(mute)}	soft mute start voltage	see Fig.12; voltage at pin LEVEL that causes $\alpha_{mute} = 3 \text{ dB}$; MSL[1:0] = 11				
		MST[2:0] = 000	-	0.75	-	V
		MST[2:0] = 001	-	0.88	-	V
		MST[2:0] = 010	-	1	-	V
		MST[2:0] = 011	-	1.12	-	V
		MST[2:0] = 100	-	1.25	-	V
		MST[2:0] = 101	-	1.5	-	V
		MST[2:0] = 110	-	1.75	-	V
		MST[2:0] = 111	-	2	-	V
C _{mute}	soft mute slope $C_{mute} = \frac{\Delta \alpha_{mute}}{\Delta V_{eq}}$	see Fig.13; slope of soft mute attenuation with respect to level voltage; MST[2:0] = 000				
	eq	MSL[1:0] = 00	-	8	_	dB/V
		MSL[1:0] = 01	-	16	_	dB/V
		MSL[1:0] = 10	-	24	-	dB/V
		MSL[1:0] = 11	-	32	_	dB/V
$\alpha_{mute(max)}$	maximum soft mute attenuation by USN	see Fig.14; f _{MPXRDS} = 150 kHz; V _{MPXRDS} = 0.6 V (RMS); USS[1:0] = 11				
		UMD[1:0] = 00	_	3	_	dB
		UMD[1:0] = 01	_	6	_	dB
		UMD[1:0] = 10	-	9	_	dB
		UMD[1:0] = 11	-	12	_	dB
V _{start(SNC)}	SNC stereo blend start voltage	see Fig.7; voltage at pin LEVEL that causes channel separation = 10 dB; SSL[1:0] = 10				
		SST[3:0] = 0000	_	1.5	_	V
		:	-	:	_	V
		SST[3:0] = 1000	_	2.0	_	V
		:	_	:	_	V
		SST[3:0] = 1111	-	2.45	-	V
C _{SNC}	$\label{eq:SNC_slope} \begin{split} \text{SNC slope} \\ \text{C}_{\text{SNC}} &= \frac{\Delta \alpha_{\text{cs}}}{\Delta V_{\text{eq}}} \end{split}$	see Fig.8; slope of channel separation between 30 dB and 10 dB with respect to level voltage; SST[3:0] = 1010				
		SSL[1:0] = 00	-	38	-	dB/V
		SSL[1:0] = 01	-	51	-	dB/V
		SSL[1:0] = 10	-	63	-	dB/V
		SSL[1:0] = 11	-	72	_	dB/V

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{start(HCC)}	HCC start voltage	see Fig.9; f_{audio} = 10 kHz; voltage at pin LEVEL that causes α_{HCC} = 3 dB; HSL[1:0] = 10				
		HST[2:0] = 000	_	1.17	_	V
		HST[2:0] = 001	_	1.42	_	V
		HST[2:0] = 010	-	1.67	_	V
		HST[2:0] = 011	-	1.92	_	V
		HST[2:0] = 100	-	2.17	-	V
		HST[2:0] = 101	-	2.67	-	V
		HST[2:0] = 110	-	3.17	-	V
		HST[2:0] = 111	-	3.67	-	V
C _{HCC}	HCC slope $\Delta \alpha_{\rm HCC}$	see Fig.10; f _{audio} = 10 kHz; HST[2:0] = 010				
	$C_{HCC} = \frac{\Delta \alpha_{HCC}}{\Delta V_{eq}}$	HSL[1:0] = 00	-	9	-	dB/V
		HSL[1:0] = 01	-	11	-	dB/V
		HSL[1:0] = 10	-	14	-	dB/V
		HSL[1:0] = 11	-	18	-	dB/V
$\alpha_{HCC(max)}$	maximum HCC	see Fig.10; f _{audio} = 10 kHz				
	attenuation	HCSF = 1	-	10	-	dB
		HCSF = 0	-	14	-	dB
f _{cut-off}	cut-off frequency of fixed HCC	see Table 31; –3 dB point (first order filter)				
		HCF[2:0] = 000	-	1.5	-	kHz
		HCF[2:0] = 001	-	2.2	-	kHz
		HCF[2:0] = 010	-	3.3	-	kHz
		HCF[2:0] = 011	-	4.7	-	kHz
		HCF[2:0] = 100	-	6.8	-	kHz
		HCF[2:0] = 101	-	10	-	kHz
		HCF[2:0] = 110	-	wide	-	-
		HCF[2:0] = 111	-	unlimited	-	-
Analog-to-dig	ital converters for I ² C-bus					
LEVEL ANALOG-	TO-DIGITAL CONVERTER (8-BIT)	; see Fig.4				
$V_{\text{LEVEL}(min)}$	lower voltage limit of conversion range		-	0.25	-	V
V _{LEVEL(max)}	upper voltage limit of conversion range		-	4.25	-	V
ΔV_{LEVEL}	bit resolution voltage		-	15.7	-	mV

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
ULTRASONIC NO	SE ANALOG-TO-DIGITAL CONVE	ERTER (4-BIT); see Fig.5			!	1
V _{USN(min)(rms)}	conversion range lower voltage limit (RMS value)	f _{FMMPX} = 150 kHz	_	0	-	V
V _{USN(max)(rms)}	conversion range upper voltage limit (RMS value)	f _{FMMPX} = 150 kHz	-	0.75	-	V
$\Delta V_{\text{USN(rms)}}$	bit resolution voltage (RMS value)		_	50	-	mV
WIDEBAND AM A	NALOG-TO-DIGITAL CONVERTE	:R (4-віт); see Fig.6	ł	•	ł	
VWAM(min)(p-p)	lower voltage limit of conversion range (peak-to-peak value)	f _{LEVEL} = 21 kHz	-	0	-	mV
VWAM(max)(p-p)	upper voltage limit of conversion range (peak-to-peak value)	f _{LEVEL} = 21 kHz	-	800	-	mV
$\Delta V_{WAM(p-p)}$	bit resolution voltage (peak-to-peak value)		_	53.3	-	mV
Tone/volume c	ontrol		•			
Z _i	input impedance at pins TAPEL, TAPER, CDL and CDR		80	-	-	kΩ
	input impedance at pin PHONE		50	-	-	kΩ
Zo	output impedance at pins LFOUT, RFOUT, LROUT and RROUT		-	-	100	Ω
G _{s(main)}	signal gain from main source input to LFOUT, RFOUT, LROUT and RROUT outputs		-1	-	+1	dB
G _{s(NAV)}	signal gain from NAV input to LFOUT, RFOUT, LROUT and RROUT outputs		-1.5	0	+1.5	dB
V _{i(max)(rms)}	maximum input voltage level at pins TAPEL, TAPER, CDL, CDR and PHONE (RMS value)	THD = 0.1%; G _{vol} = -6 dB	2	-	-	V
V _{i(NAV)(max)(rms)}	maximum input voltage level at pin NAV (RMS value)	THD = 1%	0.3	-	-	V
V _{o(max)(rms)}	maximum output voltage	THD = 0.1%; G _{vol} = +6 dB	2	-	_	V
	(RMS value)	worst case load: $R_L = 2 k\Omega$, $C_L = 10 nF$, THD = 1%	2	-	_	V

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
f _{max}	frequency response (pins TAPER, TAPEL, CDR and CDL)	upper –0.5 dB point; referenced to 1 kHz	20	-	-	kHz
CMRR	common mode rejection ratio	f _{audio} = 20 Hz to 20 kHz on CD and PHONE inputs				
		G _{vol} = 0 dB	40	_	_	dB
		$G_{vol} = -15 \text{ dB}$	55	_	-	dB
α _{cs}	channel separation	f _{audio} = 20 Hz to 20 kHz	60	80	-	dB
α _S	input isolation of one	f _{audio} = 1 kHz	90	105	-	dB
	selected source to any	$f_{audio} = 20$ Hz to 10 kHz	75	90	-	dB
	other input	f _{audio} = 20 kHz	70	-	-	dB
THD	total harmonic distortion	TAPE and CD inputs				
		f _{audio} = 20 Hz to 10 kHz; V _i = 1 V (RMS)	-	0.01	0.1	%
		$f_{audio} = 1 \text{ kHz}; V_i = 2 \text{ V (RMS)};$ $G_{vol} = 0 \text{ dB}$	-	0.02	0.1	%
		f _{audio} = 20 Hz to 10 kHz; V _i = 2 V (RMS); G _{vol} = -10 dB	-	0.02	0.2	%
		$f_{audio} = 25 \text{ Hz}; V_i = 500 \text{ mV} \text{ (RMS)};$ $G_{bass} = +8 \text{ dB}; G_{vol} = 0 \text{ dB}$	_	0.05	0.2	%
		$f_{audio} = 4 \text{ kHz}; V_i = 500 \text{ mV} \text{ (RMS)};$ $G_{treble} = +8 \text{ dB}; G_{vol} = 0 \text{ dB}$	-	0.01	0.2	%
		NAV input; $f_{audio} = 1 \text{ kHz}$; V _o = 300 mV (RMS)	-	_	1	%
V _{noise(rms)}	noise voltage (RMS value)	CCIR-ARM weighted and 20 kHz 'brick wall' without input signal and shorted AF inputs				
		G _{vol} = 0 dB	-	12	20	μV
		G_{bass} = +6 dB; G_{treble} = +6 dB; G_{vol} = 0 dB	-	24	35	μV
		G _{vol} = 20 dB; TAPE input (stereo)	-	71	100	μV
		G _{vol} = 20 dB; CD input (quasi-differential)	-	100	140	μV
		$G_{vol} = -10 \text{ dB}$	_	10	18	μV
		$G_{vol} = -40 \text{ dB}; G_{loudness} = -20 \text{ dB}$	_	9.5	13.5	μV
		outputs muted	_	5	12	μV
		using 'A-weighting' filter and 20 kHz 'brick wall'; $G_{vol} = -10 \text{ dB}$; $G_{loudness} = -10 \text{ dB}$	-	6.8	10	μV
		NAV input	_	16	40	μV
∆G _{step}	step error (all controls)	G = +20 to -36 dB	_		0.5	dB
— ⊂ siep	between all adjoining steps, all outputs	G = -36 to -59 dB	-	-	1.0	dB

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
TC _{ASI}	ASI time constant	see Table 42				
	(switching time from any	AST[1:0] = 00	-	1	_	ms
	setting to any other setting)	AST[1:0] = 01	-	3	_	ms
	Setting)	AST[1:0] = 10	-	10	_	ms
		AST[1:0] = 11	-	30	_	ms
V _{offset(max)}	maximum DC offset	between any two settings (non-consecutive) on any one audio control or any one dynamic weak signal processing control	_	7	_	mV
PSRR	power supply ripple	$V_{CC(AC)} = V_{ripple} = 200 \text{ mV} (RMS)$				
	rejection	f _{ripple} = 20 to 100 Hz	35	46	-	dB
		f _{ripple} = 1 kHz	50	75	-	dB
		f _{ripple} = 1 to 20 kHz	50	65	-	dB
α_{ct}	crosstalk between bus inputs and signal outputs	f _{clk} = 100 kHz; note 3	-	110	-	dB
t _{turn-on}	turn-on time from V _{CC} applied to 66% final DC voltage at outputs		-	100	-	ms
LOUDNESS				•	•	•
f _{loudness(low)}	loudness low boost	amplitude decrease = -3 dB				
	frequency without	LLF = 0	_	50	_	Hz
	influence of coupling capacitors	LLF = 1	_	100	-	Hz
f _{loudness} (high)	loudness filter response without influence of coupling capacitors	amplitude decrease = -1 dB; frequency referred to 100 kHz; high boost on	-	10	-	kHz
G _{loudness}	loudness gain control	f _{loudness(low)} = 50 Hz; high boost on; see Fig.16				
		maximum setting; 1 kHz tone	_	0	_	dB
		minimum setting; 1 kHz tone	-	-20	_	dB
		minimum setting; 50 Hz tone	_	-3	_	dB
		minimum setting; 10 kHz tone	-	-16	_	dB
		minimum setting; 100 kHz tone	_	–15	_	dB
		step size; 1 kHz tone	_	1	_	dB
VOLUME				•		
G _{vol}	volume/balance gain	see Table 48				
	control	maximum setting	-	20	-	dB
		minimum setting	-	-59	-	dB
		mute attenuation; 20 Hz to 20 kHz input	_	-80	-70	dB
G _{step(vol)}	step resolution gain (volume)	see Table 48	-	1	-	dB

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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	
ΔG_{set}	gain set error	G_{vol} = +20 to -36 dB	-1	0	+1	dB
		$G_{vol} = -36$ to -59 dB	-3	0	+3	dB
ΔG_{track}	gain tracking error	G_{vol} = +20 to -36 dB	-	0	1	dB
	between left and right	$G_{vol} = -36 \text{ to } -59 \text{ dB}$	_	0	3	dB
TREBLE			•	·	·	•
f _{cut-off(treble)}	treble control filter cut-off frequency	see Table 52; –3 dB frequency referenced to 100 kHz				
		TRF[1:0] = 00	-	8	-	kHz
		TRF[1:0] = 01	-	10	-	kHz
		TRF[1:0] = 10	-	12	_	kHz
		TRF[1:0] = 11	-	15	-	kHz
G _{treble}	treble gain control	see Table 51				
		maximum setting	_	14	-	dB
		minimum setting	_	-14	-	dB
$G_{step(treble)}$	step resolution gain (treble)	see Table 51	-	2	-	dB
Bass			•	1		
f _{c(bass)}	bass control filter centre	see Table 56				
	frequency	BAF[1:0] = 00	_	60	_	Hz
		BAF[1:0] = 01	_	80	_	Hz
		BAF[1:0] = 10	_	100	_	Hz
		BAF[1:0] = 11	_	120	_	Hz
Q _{bass}	bass filter quality factor	G _{bass} = +12 dB	_	1.0	_	_
EQ _{bow}	equalizer bowing		_	1.8	-	dB
G _{bass}	bass gain control	see Table 55				<u> </u>
		maximum setting; symmetrical boost	_	14	-	dB
		minimum setting; asymmetrical cut	_	-14	_	dB
		minimum setting; symmetrical cut	_	-14	_	dB
G _{step(bass)}	step resolution gain (bass)	see Table 55	-	2	-	dB
FADER		·		•		
G _{fader}	fader gain control	see Table 59				
		maximum setting	-	0	-	dB
		minimum setting	_	-59	-	dB
		mute attenuation; 20 Hz to 20 kHz input	_	-80	-66	dB

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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G _{step(fader)}	step resolution gain	see Table 59				
	(fader)	G _{fader} = 0 to −15 dB	_	1	_	dB
		G _{fader} = −15 to −45 dB	_	2.5	_	dB
		G _{fader} = −45 to −51 dB	_	3	_	dB
		$G_{fader} = -51$ to -59 dB	_	4	_	dB
α _{mute}	audio mute	volume control: mute and output muted (bits MULF, MURF, MULR and MURR)	90	-	-	dB
BEEP			•			
f _{beep}	beep generator frequency	see Table 68				
		BEF[1:0] = 00	_	500	_	Hz
		BEF[1:0] = 01	_	1	_	kHz
		BEF[1:0] = 10	_	2	_	kHz
		BEF[1:0] = 11	_	3	_	kHz
V _{beep(rms)}	beep generator audio	see Table 67				
	level (RMS value)	BEL[2:0] = 000	-	0	_	mV
		BEL[2:0] = 001	-	13.3	-	mV
		BEL[2:0] = 010	-	18	-	mV
		BEL[2:0] = 011	-	28	-	mV
		BEL[2:0] = 100	-	44	-	mV
		BEL[2:0] = 101	-	60	-	mV
		BEL[2:0] = 110	-	90	-	mV
		BEL[2:0] = 111	-	150	-	mV
THD _{beep}	total harmonic distortion of beep generator	f _{beep} = 1 kHz or 2 kHz	-	-	7	%
Power-on res	et (all registers in default se	etting, outputs muted, standby mo	de)			
V _{th(POR)}	threshold voltage of Power-on reset		-	6.3	-	V

Notes

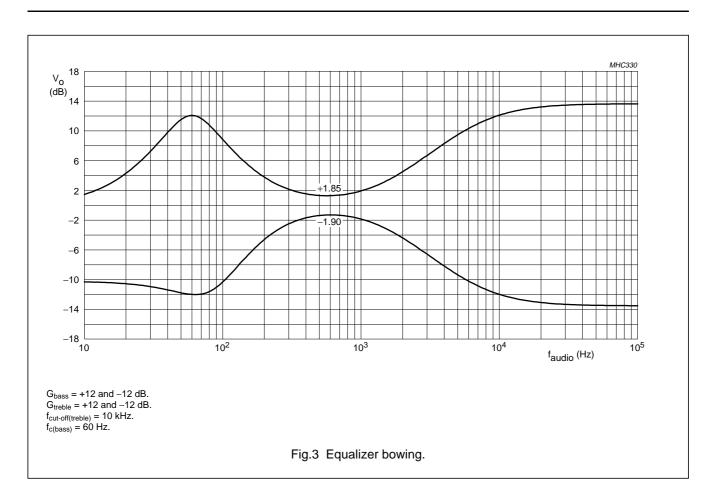
1. The LOW voltage of pin SCLG is influenced by V_{SCL}: $V_{SCLG(LOW)} \ge V_{SCL(LOW)} + 0.22$ V.

2. The equivalent level voltage is that value of the level voltage (at pin LEVEL) which results in the same weak signal control effect (for instance HCC roll-off) as the output value of the specified detector (USN, WAM and MPH).

3. Crosstalk between bus inputs and signal outputs:
$$\alpha_{ct} = 20 \log \frac{V_{bus(p-p)}}{V_{o(rms)}}$$

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Table 1 Write mode

S ⁽¹⁾	address (write)	A ⁽²⁾	subaddress	A ⁽²⁾	data byte(s)	A ⁽²⁾	P ⁽³⁾
Notes							
1. S=S	START condition.						
2. A = a	acknowledge.						
3. P=\$	STOP condition.						
Table 2	Read mode						
S ⁽¹⁾	address (read)	A ⁽²⁾	data byte(s)	A ⁽²⁾	data byte	NA ⁽³⁾	P ⁽⁴⁾

Notes

- 1. S = START condition.
- 2. A = acknowledge.
- 3. NA = not acknowledge.
- 4. P = STOP condition.

Table 3IC address byte

			IC ADDRESS				MODE
0	0	1	1	0	0	ADDR	R/W

Table 4 Description of IC address byte

BIT	SYMBOL	DESCRIPTION
7 to 2	—	001100+(ADDR) = IC address.
1	ADDR	Address bit. 0 = pin ADDR is grounded; 1 = pin ADDR is floating.
0	R/W	Read/Write. 0 = write mode; 1 = read mode.

11.1 Read mode

11.1.1 DATA BYTE 1; STATUS

Table 5 Format of data byte 1

BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
STIN	ASIA	AFUS	POR	—	ID2	ID1	ID0

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Table 6 Description of data byte	Table 6	Description	of data	byte	1
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BIT	SYMBOL	DESCRIPTION
7	STIN	Stereo indicator. 0 = no pilot signal detected; 1 = pilot signal detected.
6	ASIA	ASI active. 0 = not active; 1 = ASI step is in progress.
5	AFUS	AF update sample. 0 = LEV, USN and WAM information is taken from main frequency (continuous mode); 1 = LEV, USN and WAM information is taken from alternative frequency. Continuous mode during AF update and sampled mode after AF update. Sampled mode reverts to continuous main frequency information after read.
4	POR	Power-on reset. $0 =$ standard operation (valid I ² C-bus register settings); 1 = Power-on reset detected since last read cycle (I ² C-bus register reset). After read the bit will reset to POR = 0.
3	—	Reserved.
2 to 0	ID[2:0]	Identification. TEF6894H device type identification; ID[2:0] = 100.

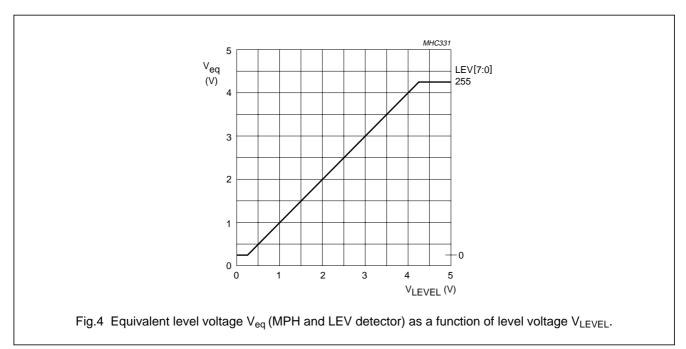
11.1.2 DATA BYTE 2; LEVEL

Table 7Format of data byte 2

BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
LEV7	LEV6	LEV5	LEV4	LEV3	LEV2	LEV1	LEV0

Table 8 Description of data byte 2

BIT	SYMBOL	DESCRIPTION
7 to 0	LEV[7:0]	Level. 8-bit value of level voltage from tuner; see Fig.4.



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11.1.3 DATA BYTE 3; USN AND WAM

Table 9Format of data byte 3

BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
USN3	USN2	USN1	USN0	WAM3	WAM2	WAM1	WAM0

Table 10 Description of data byte 3

BIT	SYMBOL	DESCRIPTION
7 to 4	USN[3:0]	Ultrasonic noise detector. USN content of the MPXRDS audio signal; see Fig.5.
3 to 0	WAM[3:0]	Wideband AM detector. WAM content of the LEVEL voltage; see Fig.6.

11.2 Write mode

Table 11 Format for subaddress byte with default setting

BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
AIOF	GATE	SGAT	SA4	SA3	SA2	SA1	SA0
_	0	0	-	_	_	-	—

Table 12 Description of subaddress byte

BIT	SYMBOL	DESCRIPTION
7	AIOF	Auto-increment off. 0 = auto-increment enabled; 1 = auto-increment disabled.
6	GATE	Gate. $0 = I^2C$ -bus outputs (SDAG and SCLG) are controllable by the shortgate or the autogate function; $1 = I^2C$ -bus outputs are enabled.
5	SGAT	Shortgate. $1 = I^2C$ -bus outputs (SDAG and SCLG) are enabled for a single transmission following this control and disabled automatically.
4 to 0	SA[4:0]	Data byte select. The subaddress value is auto-incremented when AIOF = 0 and will revert from SA = 30 to SA = 0. SA = 31 can only be accessed via direct subaddress selection, in which case auto-increment will revert from SA = 31 to SA = 0; see Table 13.

Table 13 Selection of data byte

SA4	SA3	SA2	SA1	SA0	HEX ⁽¹⁾	MNEMONIC	ADDRESSED DATA BYTE		
0	0	0	1	0	2	RDSCLK	test control		
0	0	1	0	0	4	CONTROL	control of supply and AF update		
0	0	1	0	1	5	CSALIGN	alignment of stereo channel separation		
0	0	1	1	0	6	MULTIPATH	control of weak signal sensitivity and timing		
0	0	1	1	1	7	SNC	alignment of SNC start and slope		
0	1	0	0	0	8	HIGHCUT	alignment of HCC start and slope		
0	1	0	0	1	9	SOFTMUTE	alignment soft mute start and slope		
0	1	0	1	0	A	RADIO	control of radio functions		
0	1	0	1	1	В	INPUT/ASI	input selector and ASI settings		
0	1	1	0	0	С	LOUDNESS	loudness control		
0	1	1	0	1	D	VOLUME	volume control		

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SA4	SA3	SA2	SA1	SA0	HEX ⁽¹⁾	MNEMONIC	ADDRESSED DATA BYTE
0	1	1	1	0	E	TREBLE	treble control
0	1	1	1	1	F	BASS	bass control
1	0	0	0	0	10	FADER	fader control
1	0	0	0	1	11	BALANCE	balance control
1	0	0	1	0	12	MIX	control of output mixer
1	0	0	1	1	13	BEEP	beep generator settings
1	1	1	1	1	1F	AUTOGATE	autogate control

Note

1. Data bytes 0, 1, 2 and 3 must not be used in the application. All bits in these bytes must be set to logic 0.

11.2.1 SUBADDRESS 2H; RDSCLK

Table 14	Format of data b	byte 2H with default setting
----------	------------------	------------------------------

BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
_	—	TST3	TST2	TST1	TST0	—	_
_	—	0	0	0	0	—	_

Table 15 Description of data byte 2H

BIT	SYMBOL	DESCRIPTION				
7 and 6	—	Not used. Set to logic 0.				
5 to 2	TST[3:0]	Test. TST[3:0] = 0000: normal operation.				
1 and 0	—	Not used. Set to logic 0.				

11.2.2 SUBADDRESS 4H; CONTROL

Table 16 Format of data byte 4H with default setting

BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
_	STBA	AFUM	AFUH	RMUT	—	LETF	ATTB
_	1	0	0	0	-	0	0

Table 17 Description of data byte 4H

BIT	SYMBOL	DESCRIPTION
7	_	Not used. Set to logic 0.
6	STBA	Standby mode audio processing. 0 = audio processing active; 1 = audio processing in standby mode (audio inputs and outputs at DC).
5	AFUM	Enables AF update mute. 0 = AF update mute disabled; 1 = AF update mute enabled (controlled by AFSAMP and AFHOLD input).
4	AFUH	AF update hold function. 0 = disable, the weak signal processing hold is controlled by the AFHOLD input only; 1 = hold. This is equal to taking the AFHOLD input LOW. The bit is reset to 0, when AFHOLD input is set to LOW (i.e. at AF update or preset change).
3	RMUT	Radio signal mute. 0 = no mute; 1 = mute with 1 ms ASI slope at start and stop.

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BIT	SYMBOL	DESCRIPTION
2	_	Not used. Set to logic 0.
1	LETF	Fast level detector time constants. 0 = slow level detector time constants are used; 1 = fast level detector time constants are used. See Table 24.
0	ATTB	Attack bound of the MPH and LEV detector. 0 = detectors are unbounded; 1 = range of the MPH and LEV detector are limited in their range for immediate start of attack. In AM mode the detectors are always unbounded.

11.2.3 SUBADDRESS 5H; CSALIGN

Table 18 Format of data byte 5H with default setting

BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
CSR1	CSR0	CSA3	CSA2	CSA1	CSA0	_	_
0	1	0	1	1	1	_	_

Table 19 Description of data byte 5H

BIT	SYMBOL	DESCRIPTION
7 and 6	CSR[1:0]	FM stereo channel separation (high frequency). See Table 20.
5 to 2	CSA[3:0]	FM stereo channel separation and adjustment. See Table 21.
1 and 0	—	Not used. Set to logic 0.

Table 20 FM stereo channel separation

CSR1	CSR0	FM STEREO CHANNEL SEPARATION (dB)
0	0	0
0	1	0.4
1	0	0.8
1	1	1.2

Table 21 FM stereo channel separation and adjustment

CSA3	CSA2	CSA1	CSA0	FM STEREO CHANNEL SEPARATION AND ADJUSTMENT (dB)
0	0	0	0	0
0	0	0	1	0.2
:	:	:	:	:
1	1	1	0	2.8
1	1	1	1	3.0

11.2.4 SUBADDRESS 6H; MULTIPATH

Table 22 Format of data byte 6H with default setting

BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
USS1	USS0	WAS1	WAS0	LET1	LET0	MPT1	MPT0
0	1	0	1	0	0	0	0

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Table 23 Description of data byte 6H

BIT	SYMBOL	DESCRIPTION
7 and 6	USS[1:0]	USN sensitivity for weak signal processing. See Fig.5.
5 and 4	WAS[1:0]	WAM sensitivity for weak signal processing. See Fig.6.
3 and 2	LET[1:0]	LEVEL detector time constant. See Table 24.
1 and 0	MPT[1:0]	MPH detector time constants (level, WAM and USN). See Table 25.

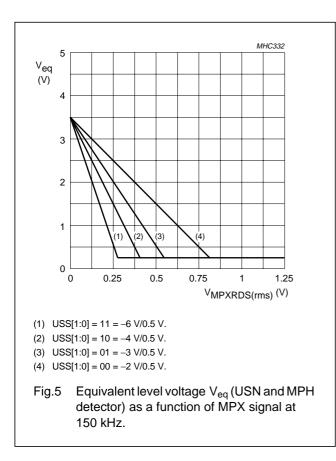
Table 24 Setting of the time constants of the LEVEL detector

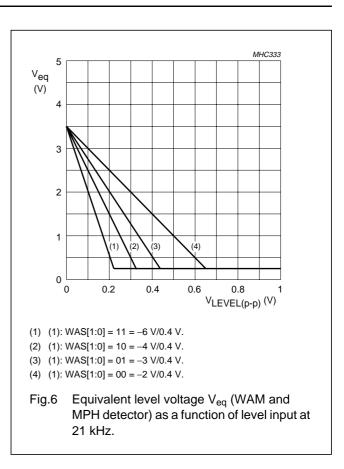
LETF	LET1	LET0	t _{LEVEL} (s)		
LEIF		LEIU	ATTACK	DECAY	
0	0	0	3	3	
0	0	1	3	6	
0	1	0	1.5	1.5	
0	1	1	0.5	1.5	
1	0	0	0.5	0.5	
1	0	1	0.17	0.5	
1	1	0	0.06	0.17	
1	1	1	0.06	0.06	

 Table 25
 Setting of the time constants of the MPH detector (level, WAM and USN)

MPT1	МРТО	t _{MPH} (s)		
	WIF TO	ATTACK	DECAY	
0	0	0.5	12	
0	1	0.5	24	
1	0	0.5	6	
1	1	0.25	6	

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11.2.5 SUBADDRESS 7H; SNC

Table 26 Format of data byte 7H with default setting

BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
SST3	SST2	SST1	SST0	SSL1	SSL0	HCMP	HCSF
0	1	1	1	0	1	0	0

Table 27 Description of data byte 7H

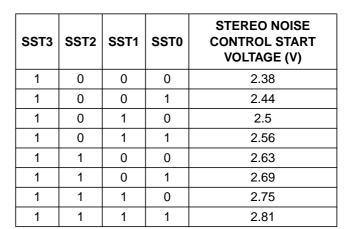
BIT	SYMBOL	DESCRIPTION
7 to 4	SST[3:0]	Start of the stereo blend SNC. See Table 28 and Fig.7.
3 and 2	SSL[1:0]	Slope of the stereo blend SNC. See Fig.8.
1	HCMP	High cut control source. 0 = control by the level (LEV) detector; 1 = control by the multipath (MPH) detector.
0	HCSF	High cut control minimum bandwidth. 0 = 2 kHz; 1 = 3 kHz.

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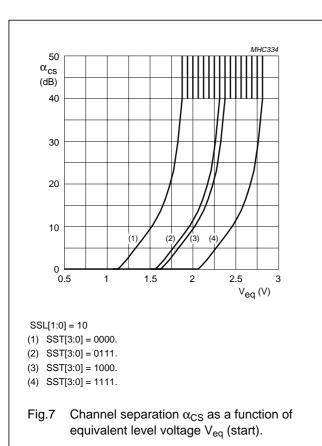
С
(

SST3	SST2	SST1	SST0	STEREO NOISE CONTROL START VOLTAGE (V)
0	0	0	0	1.88
0	0	0	1	1.94
0	0	1	0	2
0	0	1	1	2.06
0	1	0	0	2.13
0	1	0	1	2.19
0	1	1	0	2.25
0	1	1	1	2.31



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 α_{cs}



(dB) 40 30 20 (1)、 (2) < (3) 10 (4) 0 1 1.5 2 2.5 3 $V_{eq}(V)$ SST[3:0] = 1010 (1) SSL[1:0] = 00 = 38 dB/V. (2) SSL[1:0] = 01 = 51 dB/V. (3) SSL[1:0] = 10 = 63 dB/V. (4) SSL[1:0] = 11 = 72 dB/V. Fig.8 Channel separation α_{CS} as a function of equivalent level voltage V_{eq} (slope).

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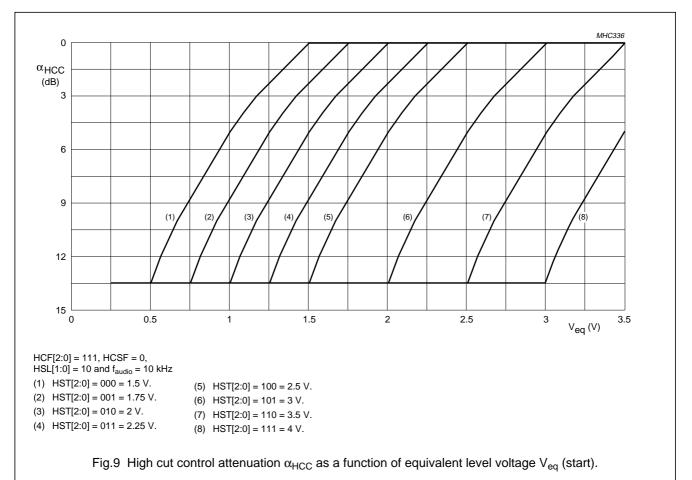
11.2.6 SUBADDRESS 8H; HIGHCUT

 Table 29
 Format of data byte 8H with default setting

BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
HST2	HST1	HST0	HSL1	HSL0	HCF2	HCF1	HCF0
0	1	1	0	1	1	1	1

 Table 30
 Description of data byte 8H

BIT	SYMBOL	DESCRIPTION
7 to 5	HST[2:0]	High cut control start (weak signal processing). See Fig.9.
4 and 3	HSL[1:0]	High cut control slope (weak signal processing). See Fig.10.
2 to 0	HCF[2:0]	Fixed high cut control (maximum HCC bandwidth). See Table 31 and Fig.11.



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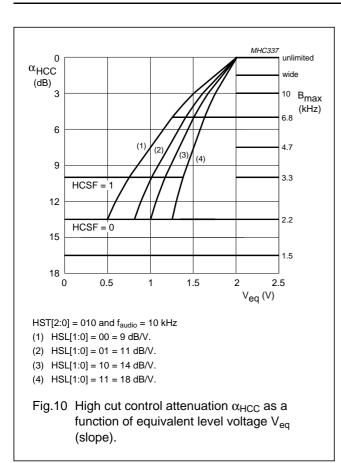
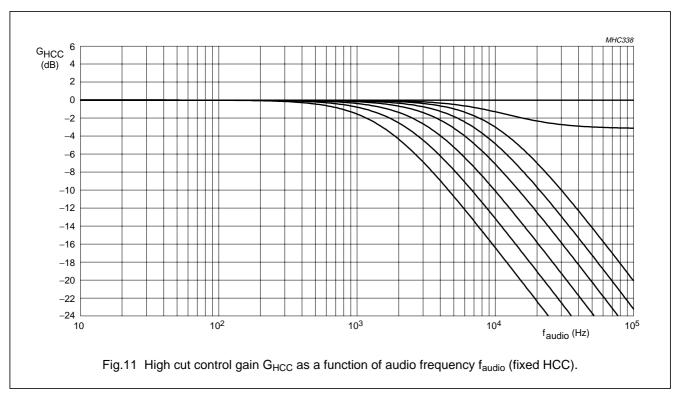


Table 31 Fixed high cut control

HCF2	HCF1	HCF0	B _{max} (kHz)
0	0	0	1.5
0	0	1	2.2
0	1	0	3.3
0	1	1	4.7
1	0	0	6.8
1	0	1	10
1	1	0	wide
1	1	1	unlimited



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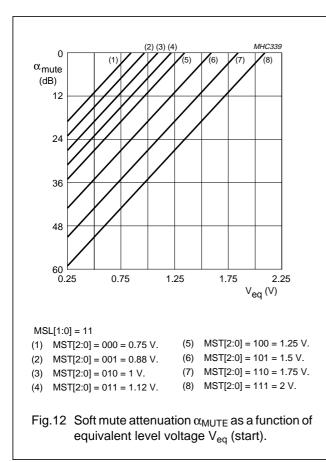
11.2.7 SUBADDRESS 9H; SOFTMUTE

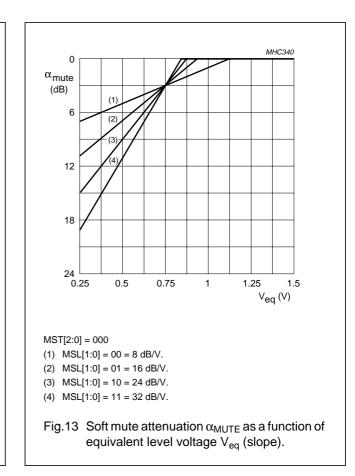
Table 32 Format of data byte 9H with default setting

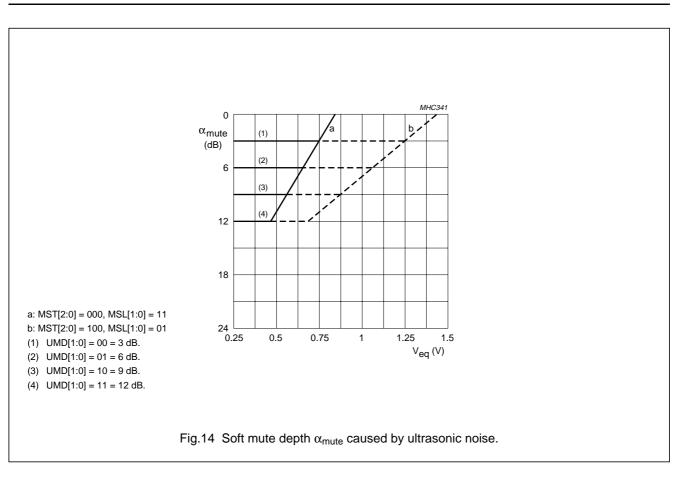
BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
MST2	MST1	MST0	MSL1	MSL0	UMD1	UMD0	SMON
0	1	1	0	1	0	1	1

Table 33 Description of data byte 9H

BIT	SYMBOL	DESCRIPTION
7 to 5	MST[2:0]	Soft mute start. α_{mute} = 3 dB; see Fig.12.
4 and 3	MSL[1:0]	Soft mute slope. See Fig.13.
2 and 1	UMD[1:0]	USN mute depth. Maximum soft mute attenuation of the soft mute via USN control; see Fig.14.
0	SMON	Soft mute enable. 0 = disable; 1 = enable.







11.2.8 SUBADDRESS AH; RADIO

Table 34 Format of data byte AH with default setting

BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
AM	MONO	DEMP	ING1	ING0	SEAR	NBS1	NBS0
0	0	1	0	0	1	1	0

Table 35 Description of data byte AH

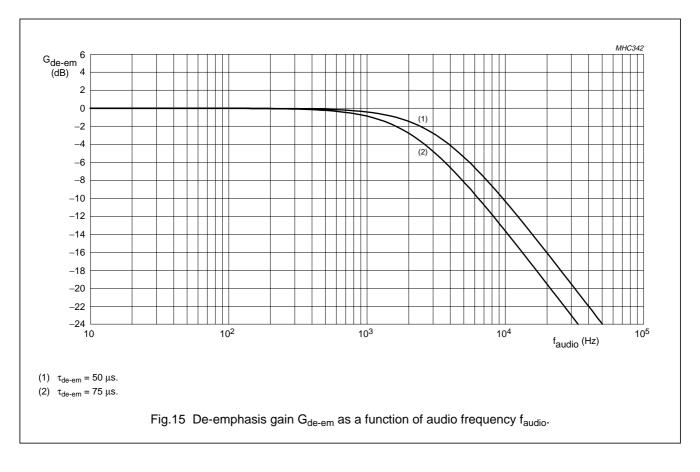
BIT	SYMBOL	DESCRIPTION			
7	AM	AM selection. 0 = FM mode selected; 1 = AM mode selected.			
6	MONO	ereo decoder mono. 0 = set to FM stereo; 1 = set to FM mono.			
5	DEMP	De-emphasis time constant. $0 = 75 \ \mu s$; $1 = 50 \ \mu s$; see Fig.15.			
4 and 3	ING[1:0]	Input gain. See Table 36.			
2	SEAR	LEVEL and MPH detector time constant. 0 = standard time constant selected; 1 = fast time constant of 60 ms selected.			
1 and 0	NBS[1:0]	AM noise blanker and the FM noise blanker MPX sensitivity. See Table 37.			

Table 36	Input gain
----------	------------

ING1	ING0	GAIN FOR FMMPX INPUT (dB)	GAIN FOR AM AND MPXRDS INPUT (dB)
0	0	0	0
0	1	3	3
1	0	6	6
1	1	23.5	0

Table 37 Noise blanker sensitivity

NBS1	NBS0	SENSITIVITY OF FM NOISE BLANKER AT MPXRDS INPUT (mV)	SENSITIVITY OF AM NOISE BLANKER (%)
0	0	90	110
0	1	150	140
1	0	210	175
1	1	270	220



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11.2.9 SUBADDRESS BH; INPUT AND ASI

Table 38 Format of data byte BH with default setting

BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
NBL1	NBL0	INP1	INP0	MUTE	ASI	AST1	AST0
1	0	0	0	1	1	0	0

Table 39 Description of data byte BH

BIT	SYMBOL	DESCRIPTION
7 and 6	NBL[1:0]	FM noise blanker level sensitivity. See Table 40.
5 and 4	INP[1:0]	Audio input tone/volume part. See Table 41.
3	MUTE	Audio mute. 0 = no mute; 1 = mute.
2	ASI	Audio step interpolation. 0 = disable; 1 = enable.
1 and 0	AST[1:0]	Audio step interpolation time constant. ASI time is 0 s when ASI = 0; see Table 42.

Table 40 FM noise blanker level sensitivity

NBL1	NBL0	SENSITIVITY OF FM NOISE BLANKER AT LEVEL INPUT (mV)
0	0	9
0	1	18
1	0	28
1	1	reserved

Table 41 Audio input tone/volume part

INP1	INP0	AUDIO INPUT FOR TONE/VOLUME PART
0	0	radio
0	1	CD
1	0	tape
1	1	phone

Table 42 Audio step interpolation time constant

AST1	AST0	ASI TIME (ms)
0	0	1
0	1	3
1	0	10
1	1	30

11.2.10 SUBADDRESS CH; LOUDNESS

 Table 43
 Format of data byte CH with default setting

BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
_	LDN4	LDN3	LDN2	LDN1	LDN0	LLF	LHB
_	0	0	0	0	0	1	1

Table 44 Description of data byte CH, see Figs 16 to 19

BIT SYMBOL DESCRIPTION 7 Not used. Set to logic 0. 6 to 2 LDN[4:0] Loudness gain. See Table 45.

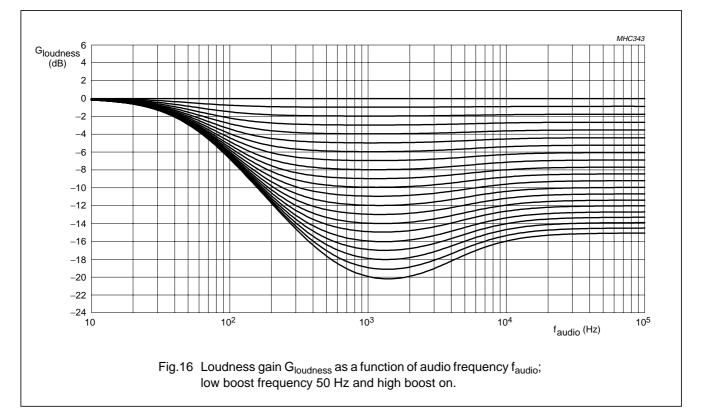
 1
 LLF
 Loudness low boost frequency. 0 = 50 Hz; 1 = 100 Hz.

 0
 LHB
 Loudness high boost enable. 0 = loudness low boost is enabled; 1 = loudness low

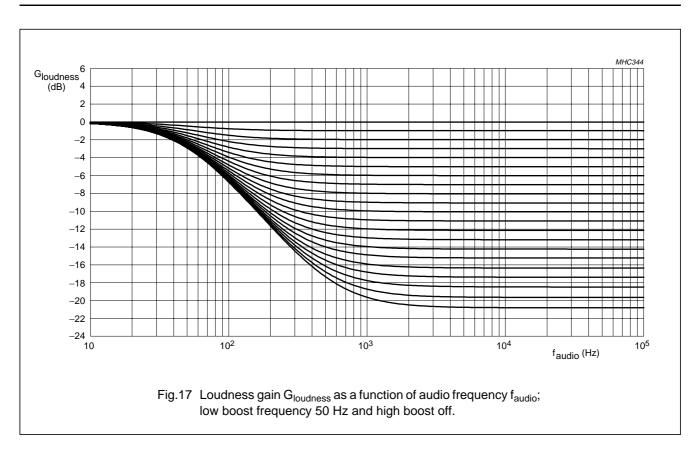
boost and loudness high boost are enabled.

Table 45 Loudness gain

LDN4	LDN3	LDN2	LDN1	LDN0	LOUDNESS CONTROL (dB)
0	0	0	0	0	0
0	0	0	0	1	-1
0	0	0	1	0	-2
:	:	:	:	:	:
1	0	0	1	0	-18
1	0	0	1	1	-19
1	0	1	0	0	-20



Product specification



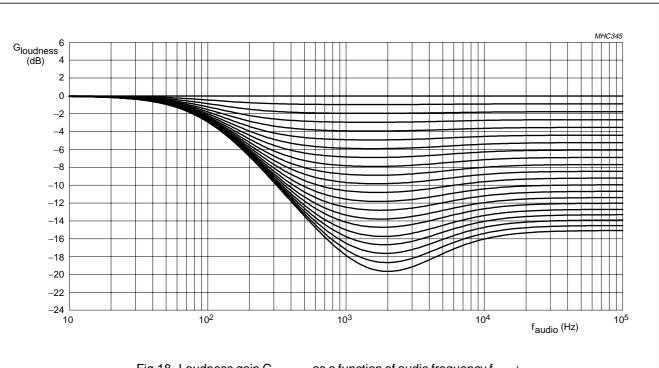
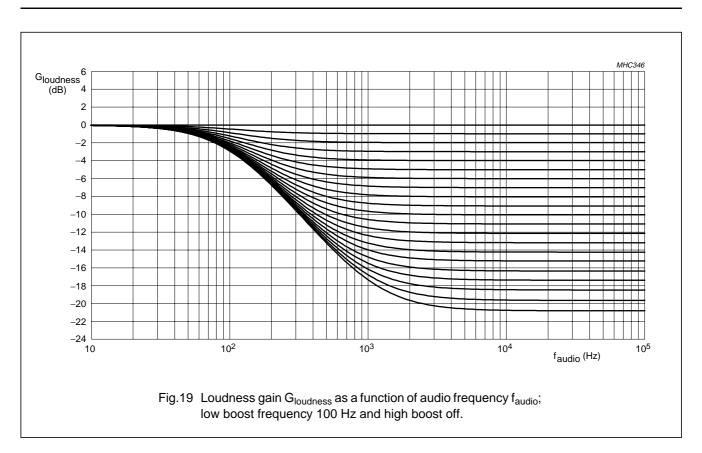


Fig.18 Loudness gain $G_{loudness}$ as a function of audio frequency f_{audio} ; low boost frequency 100 Hz and high boost on.



11.2.11 SUBADDRESS DH; VOLUME

Table 46	Format of	data byte	DH with	default setting
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BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
_	VOL6	VOL5	VOL4	VOL3	VOL2	VOL1	VOL0
_	0	1	0	0	0	0	0

Table 47 Description of data byte DH

BIT	SYMBOL	DESCRIPTION
7	—	Not used. Set to logic 0.
6 to 0	VOL[6:0]	Volume setting. See Table 48.

Table 48 Volume setting

VOL6	VOL5	VOL4	VOL3	VOL2	VOL1	VOL0	GAIN (dB)
0	0	0	1	1	0	0	20
0	0	0	1	1	0	1	19
0	0	0	1	1	1	0	18
:	:	:	:	:	:	:	:
0	0	1	1	1	1	0	2
0	0	1	1	1	1	1	1
0	1	0	0	0	0	0	0

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VOL6	VOL5	VOL4	VOL3	VOL2	VOL1	VOL0	GAIN (dB)
0	1	0	0	0	0	1	-1
0	1	0	0	0	1	0	-2
:	:	:	:	:	:	:	:
1	0	1	1	0	1	0	-58
1	0	1	1	0	1	1	-59
1	0	1	1	1	0	0	mute

11.2.12 SUBADDRESS EH; TREBLE

Table 49 Format of data byte EH with default setting

BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
_	TRE2	TRE1	TRE0	TREM	TRF1	TRF0	_
_	0	0	0	1	0	1	_

Table 50 Description of data byte EH, see Fig.20

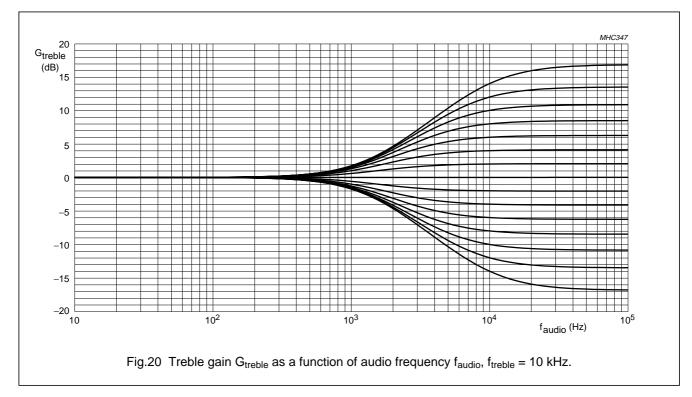
BIT	SYMBOL	DESCRIPTION
7	_	Not used. Set to logic 0.
6 to 4	TRE[2:0]	Treble gain. See Table 51.
3	TREM	Treble attenuation or gain. 0 = attenuation; 1 = gain; see Table 51.
2 and 1	TRF[1:0]	Treble frequency. See Table 52.
0	_	Not used. Set to logic 0.

Table 51 Treble gain

TRE2	TRE1	TRE0	TREM	TREBLE CONTROL (dB)
1	1	1	1	14
1	1	0	1	12
1	0	1	1	10
1	0	0	1	8
0	1	1	1	6
0	1	0	1	4
0	0	1	1	2
0	0	0	1	0
0	0	0	0	0
0	0	1	0	-2
0	1	0	0	-4
0	1	1	0	-6
1	0	0	0	-8
1	0	1	0	-10
1	1	0	0	-12
1	1	1	0	-14

Table 52 Treble frequency

TRF1	TRF0	TREBLE FREQUENCY (kHz)
0	0	8
0	1	10
1	0	12
1	1	15



11.2.13 SUBADDRESS FH; BASS

Table 53 Format of data byte FH with default setting

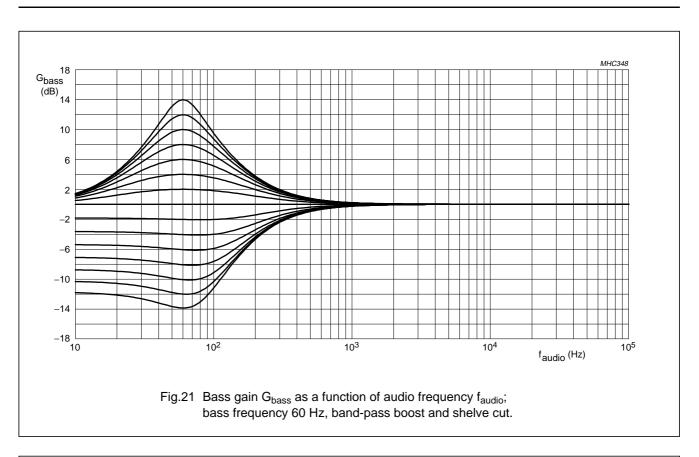
BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
_	BAS2	BAS1	BAS0	BASM	BAF1	BAF0	BASH
_	0	0	0	1	1	0	0

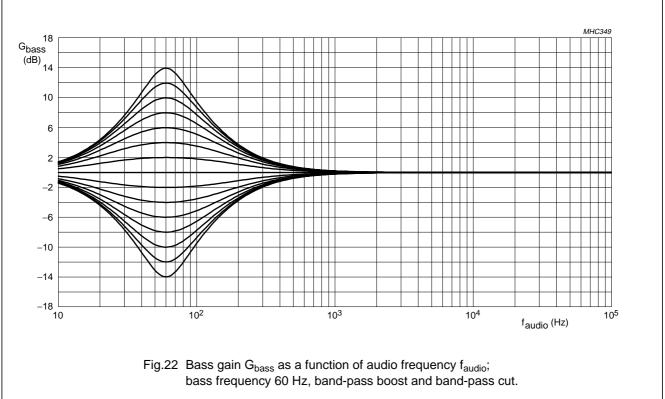
 Table 54
 Description of data byte FH, see Figs 21 and 22

BIT	SYMBOL	DESCRIPTION
7	—	Not used. Set to logic 0.
6 to 4	BAS[2:0]	Bass gain. See Table 55.
3	BASM	Bass attenuation or gain. 0 = attenuation; 1 = gain; see Table 55.
2 and 1	BAF[1:0]	Bass frequency. See Table 56.
0	BASH	Bass frequency response. 0 = band-pass; 1 = shelve curve (only guaranteed for BASM = 0).

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Table	55	Bass	gain
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BAS2	BAS1	BAS0	BASM	BASS CONTROL (dB)
1	1	1	1	14
1	1	0	1	12
1	0	1	1	10
1	0	0	1	8
0	1	1	1	6
0	1	0	1	4
0	0	1	1	2
0	0	0	1	0
0	0	0	0	0
0	0	1	0	-2
0	1	0	0	-4
0	1	1	0	-6
1	0	0	0	-8
1	0	1	0	-10
1	1	0	0	-12
1	1	1	0	-14

Table 56 Bass frequency

BAF1	BAF0	BASS FREQUENCY (Hz)
0	0	60
0	1	80
1	0	100
1	1	120

11.2.14 SUBADDRESS 10H; FADER

Table 57 Format of data byte 10H with default setting

BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
_	—	FAD4	FAD3	FAD2	FAD1	FAD0	FADM
_	—	0	0	0	0	0	1

Table 58 Description of data byte 10H

BIT	SYMBOL	DESCRIPTION
7 and 6	_	Not used. Set to logic 0.
5 to 1	FAD[4:0]	Fader gain. See Table 59.
0	FADM	Fader gain mode. 0 = front output attenuated; 1 = rear output attenuated.

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Table 59 Fader gain

FAD4	FAD3	FAD2	FAD1	FAD0	FADER CONTROL (dB)
0	0	0	0	0	0
0	0	0	0	1	-1
0	0	0	1	0	-2
:	:	:	:	:	:
0	1	1	1	0	-14
0	1	1	1	1	-15
1	0	0	0	0	-17.5
1	0	0	0	1	-20
:	:	:	:	:	:
1	1	0	1	0	-42.5
1	1	0	1	1	-45
1	1	1	0	0	-48
1	1	1	0	1	-51
1	1	1	1	0	-55
1	1	1	1	1	-59

11.2.15 SUBADDRESS 11H; BALANCE

Table 60 Format of data byte 11H with default setting

BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
BAL6	BAL5	BAL4	BAL3	BAL2	BAL1	BAL0	BALM
0	0	0	0	0	0	0	1

Table 61 Description of data byte 11H

BIT	SYMBOL	DESCRIPTION
7 to 1	BAL[6:0]	Balance gain. See Table 62.
0	BALM	Balance gain mode. 0 = left channel attenuated; 1 = right channel attenuated.

Table 62 Balance gain

BAL6	BAL5	BAL4	BAL3	BAL2	BAL1	BAL0	BALANCE CONTROL (dB)
0	0	0	0	0	0	0	0
0	0	0	0	0	0	1	-1
0	0	0	0	0	1	0	-2
:	:	:	:	:	:	:	:
1	0	0	1	1	0	1	-77
1	0	0	1	1	1	0	-78
1	0	0	1	1	1	1	-79
1	0	1	0	0	0	0	mute

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11.2.16 SUBADDRESS 12H; MIX

Table 63 Format of data byte 12H with default setting

BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
MILF	MIRF	MILR	MIRR	MULF	MURF	MULR	MURR
0	0	0	0	1	1	1	1

Table 64 Description of data byte 12H

BIT	SYMBOL	DESCRIPTION
7	MILF	Mixer left front LFOUT. 0 = no mix; 1 = mix with NAV input and BEEP.
6	MIRF	Mixer right front RFOUT. 0 = no mix; 1 = mix with NAV input and BEEP.
5	MILR	Mixer left rear LROUT. 0 = no mix; 1 = mix with NAV input and BEEP.
4	MIRR	Mixer right rear RROUT. 0 = no mix; 1 = mix with NAV input and BEEP.
3	MULF	Mutes left front LFOUT. 0 = no mute; 1 = mute except for NAV input and BEEP.
2	MURF	Mutes right front RFOUT. 0 = no mute; 1 = mute except for NAV input and BEEP.
1	MULR	Mutes left rear LROUT. 0 = no mute; 1 = mute except for NAV input and BEEP.
0	MURR	Mutes right rear RROUT. 0 = no mute; 1 = mute except for NAV input and BEEP.

11.2.17 SUBADDRESS 13H; BEEP

Table 65 Format of data byte 13H with default setting

BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
BEL2	BEL1	BEL0	BEF1	BEF0	NAV	_	_
0	0	0	0	0	0	_	_

Table 66 Description of data byte 13H

BIT	SYMBOL	DESCRIPTION
7 to 5	BEL[2:0]	Beep level. See Table 67.
4 and 3	BEF[1:0]	Beep frequency. See Table 68.
2	NAV	Mute NAV. 0 = mute; 1 = no mute.
1 and 0	—	Not used. Set to logic 0.

Table 67 Beep level

BEL2	BEL1	BEL0	BEEP LEVEL (mV)
0	0	0	mute
0	0	1	13
0	1	0	18
0	1	1	28
1	0	0	44
1	0	1	60
1	1	0	90
1	1	1	150

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Table 68 Beep frequency

BEF1	BEF0	BEEP FREQUENCY (Hz)
0	0	500
0	1	1000
1	0	2000
1	1	3000

11.2.18 SUBADDRESS 1FH; AUTOGATE

Table 69 Format of data byte 1FH with default setting

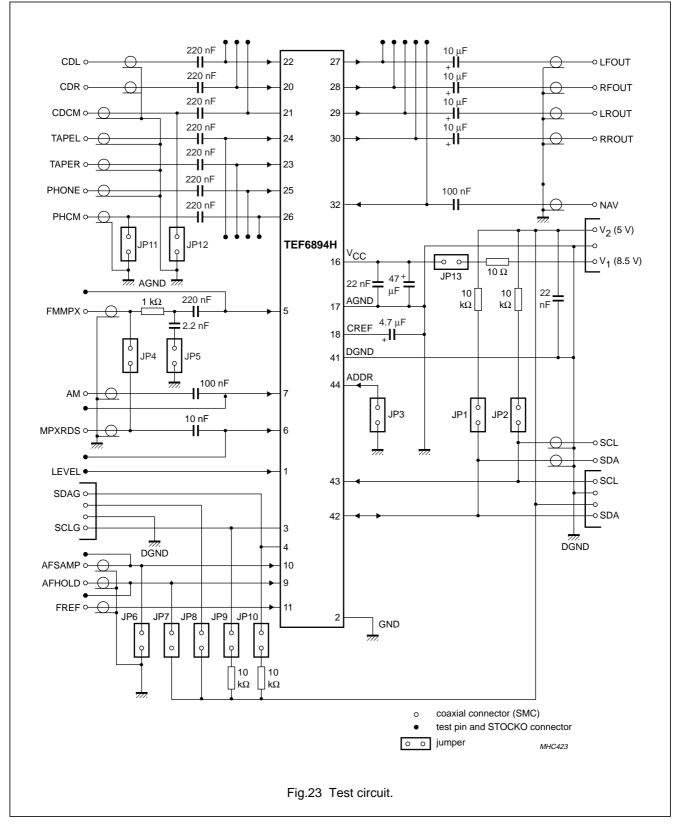
BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
AGA6	AGA5	AGA4	AGA3	AGA2	AGA1	AGA0	AGOF
_	_	-	-	_	—	_	1

Table 70 Description of data byte 1FH

BIT	SYMBOL	DESCRIPTION
7 to 1	AGA[6:0]	I²C-bus device address definition. These bits define the I ² C-bus device address definition for the automatic control of the I ² C-bus loop through gate. The subaddress auto-increment function reverts from SA = 30 to SA = 0, excluding the AUTOGATE byte (SA = 31). The AUTOGATE byte can only be accessed via direct subaddress selection of SA = 31, in which case auto-increment will revert to SA = 0.
0	AGOF	Autogate function enable. 0 = enable; 1 = disable [The autogate function is not compatible with the TEA684x tuner devices. For the TEA684x the use of the shortgate (SGAT) function is advised].

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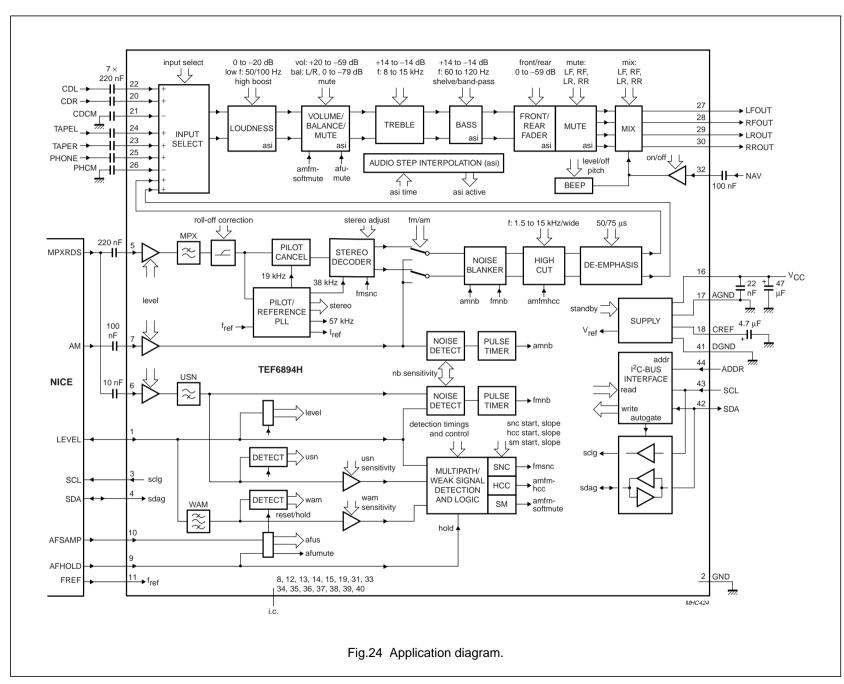
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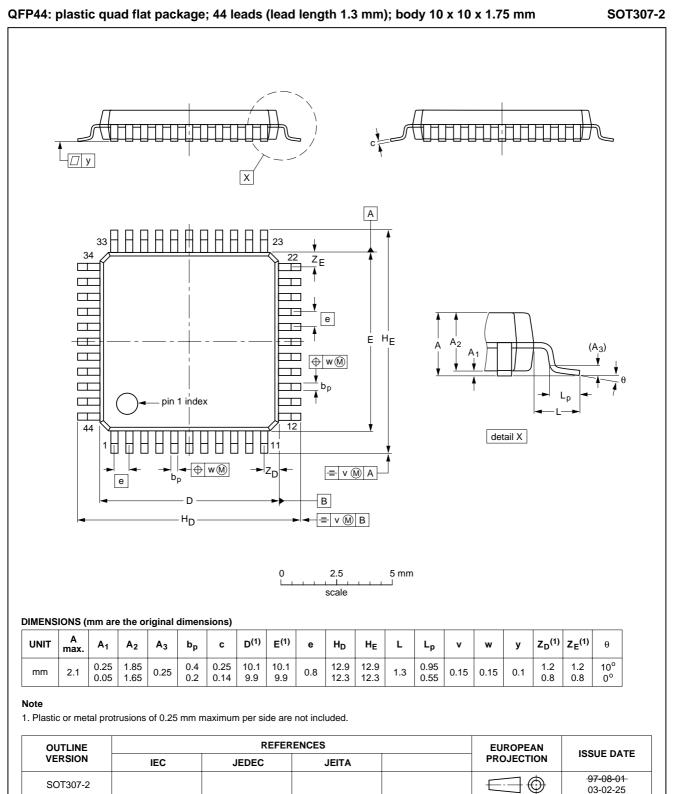
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radio integrated signal processor

Product specification

13 PACKAGE OUTLINE



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14 SOLDERING

14.1 Introduction to soldering surface mount packages

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *"Data Handbook IC26; Integrated Circuit Packages"* (document order number 9398 652 90011).

There is no soldering method that is ideal for all surface mount IC packages. Wave soldering can still be used for certain surface mount ICs, but it is not suitable for fine pitch SMDs. In these situations reflow soldering is recommended.

14.2 Reflow soldering

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement. Driven by legislation and environmental forces the worldwide use of lead-free solder pastes is increasing.

Several methods exist for reflowing; for example, convection or convection/infrared heating in a conveyor type oven. Throughput times (preheating, soldering and cooling) vary between 100 and 200 seconds depending on heating method.

Typical reflow peak temperatures range from 215 to 270 °C depending on solder paste material. The top-surface temperature of the packages should preferably be kept:

- below 225 °C (SnPb process) or below 245 °C (Pb-free process)
 - for all BGA and SSOP-T packages
 - for packages with a thickness \geq 2.5 mm
 - for packages with a thickness < 2.5 mm and a volume ≥ 350 mm³ so called thick/large packages.
- below 240 °C (SnPb process) or below 260 °C (Pb-free process) for packages with a thickness < 2.5 mm and a volume < 350 mm³ so called small/thin packages.

Moisture sensitivity precautions, as indicated on packing, must be respected at all times.

14.3 Wave soldering

Conventional single wave soldering is not recommended for surface mount devices (SMDs) or printed-circuit boards with a high component density, as solder bridging and non-wetting can present major problems. To overcome these problems the double-wave soldering method was specifically developed.

If wave soldering is used the following conditions must be observed for optimal results:

- Use a double-wave soldering method comprising a turbulent wave with high upward pressure followed by a smooth laminar wave.
- For packages with leads on two sides and a pitch (e):
 - larger than or equal to 1.27 mm, the footprint longitudinal axis is **preferred** to be parallel to the transport direction of the printed-circuit board;
 - smaller than 1.27 mm, the footprint longitudinal axis must be parallel to the transport direction of the printed-circuit board.

The footprint must incorporate solder thieves at the downstream end.

• For packages with leads on four sides, the footprint must be placed at a 45° angle to the transport direction of the printed-circuit board. The footprint must incorporate solder thieves downstream and at the side corners.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Typical dwell time of the leads in the wave ranges from 3 to 4 seconds at 250 °C or 265 °C, depending on solder material applied, SnPb or Pb-free respectively.

A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

14.4 Manual soldering

Fix the component by first soldering two diagonally-opposite end leads. Use a low voltage (24 V or less) soldering iron applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to 300 °C.

When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 $^\circ\text{C}.$

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14.5 Suitability of surface mount IC packages for wave and reflow soldering methods

PACKAGE ⁽¹⁾	SOLDERING METHOD		
FACRAGE	WAVE	REFLOW ⁽²⁾	
BGA, LBGA, LFBGA, SQFP, SSOP-T ⁽³⁾ , TFBGA, VFBGA	not suitable	suitable	
DHVQFN, HBCC, HBGA, HLQFP, HSQFP, HSOP, HTQFP, HTSSOP, HVQFN, HVSON, SMS	not suitable ⁽⁴⁾	suitable	
PLCC ⁽⁵⁾ , SO, SOJ	suitable	suitable	
LQFP, QFP, TQFP	not recommended ⁽⁵⁾⁽⁶⁾	suitable	
SSOP, TSSOP, VSO, VSSOP	not recommended ⁽⁷⁾	suitable	
PMFP ⁽⁸⁾	not suitable	not suitable	

Notes

- 1. For more detailed information on the BGA packages refer to the "(*LF*)BGA Application Note" (AN01026); order a copy from your Philips Semiconductors sales office.
- 2. All surface mount (SMD) packages are moisture sensitive. Depending upon the moisture content, the maximum temperature (with respect to time) and body size of the package, there is a risk that internal or external package cracks may occur due to vaporization of the moisture in them (the so called popcorn effect). For details, refer to the Drypack information in the "Data Handbook IC26; Integrated Circuit Packages; Section: Packing Methods".
- 3. These transparent plastic packages are extremely sensitive to reflow soldering conditions and must on no account be processed through more than one soldering cycle or subjected to infrared reflow soldering with peak temperature exceeding 217 °C ± 10 °C measured in the atmosphere of the reflow oven. The package body peak temperature must be kept as low as possible.
- 4. These packages are not suitable for wave soldering. On versions with the heatsink on the bottom side, the solder cannot penetrate between the printed-circuit board and the heatsink. On versions with the heatsink on the top side, the solder might be deposited on the heatsink surface.
- 5. If wave soldering is considered, then the package must be placed at a 45° angle to the solder wave direction. The package footprint must incorporate solder thieves downstream and at the side corners.
- 6. Wave soldering is suitable for LQFP, TQFP and QFP packages with a pitch (e) larger than 0.8 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.65 mm.
- 7. Wave soldering is suitable for SSOP, TSSOP, VSO and VSSOP packages with a pitch (e) equal to or larger than 0.65 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.5 mm.
- 8. Hot bar or manual soldering is suitable for PMFP packages.

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15 DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
11	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

Notes

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

16 DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information — Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors make no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

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18 PURCHASE OF PHILIPS I²C COMPONENTS



Purchase of Philips I²C components conveys a license under the Philips' I²C patent to use the components in the I²C system provided the system conforms to the I²C specification defined by Philips. This specification can be ordered using the code 9398 393 40011.

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Contact information

For additional information please visit http://www.semiconductors.philips.com. Fax: +31 40 27 24825 For sales offices addresses send e-mail to: sales.addresses@www.semiconductors.philips.com.

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